

FIG. 1A is a schematic diagram of a device 100 in a first state. The device 100 includes a substrate 110, a first layer 120, a second layer 130, and a third layer 140. The first layer 120 is disposed on the substrate 110, and the second layer 130 is disposed on the first layer 120. The third layer 140 is disposed on the second layer 130. The device 100 is shown in a perspective view, and the layers 110, 120, 130, and 140 are shown in cross-section. The device 100 is shown in a first state, and the layers 110, 120, 130, and 140 are shown in a first configuration. The device 100 is shown in a perspective view, and the layers 110, 120, 130, and 140 are shown in cross-section. The device 100 is shown in a first state, and the layers 110, 120, 130, and 140 are shown in a first configuration.

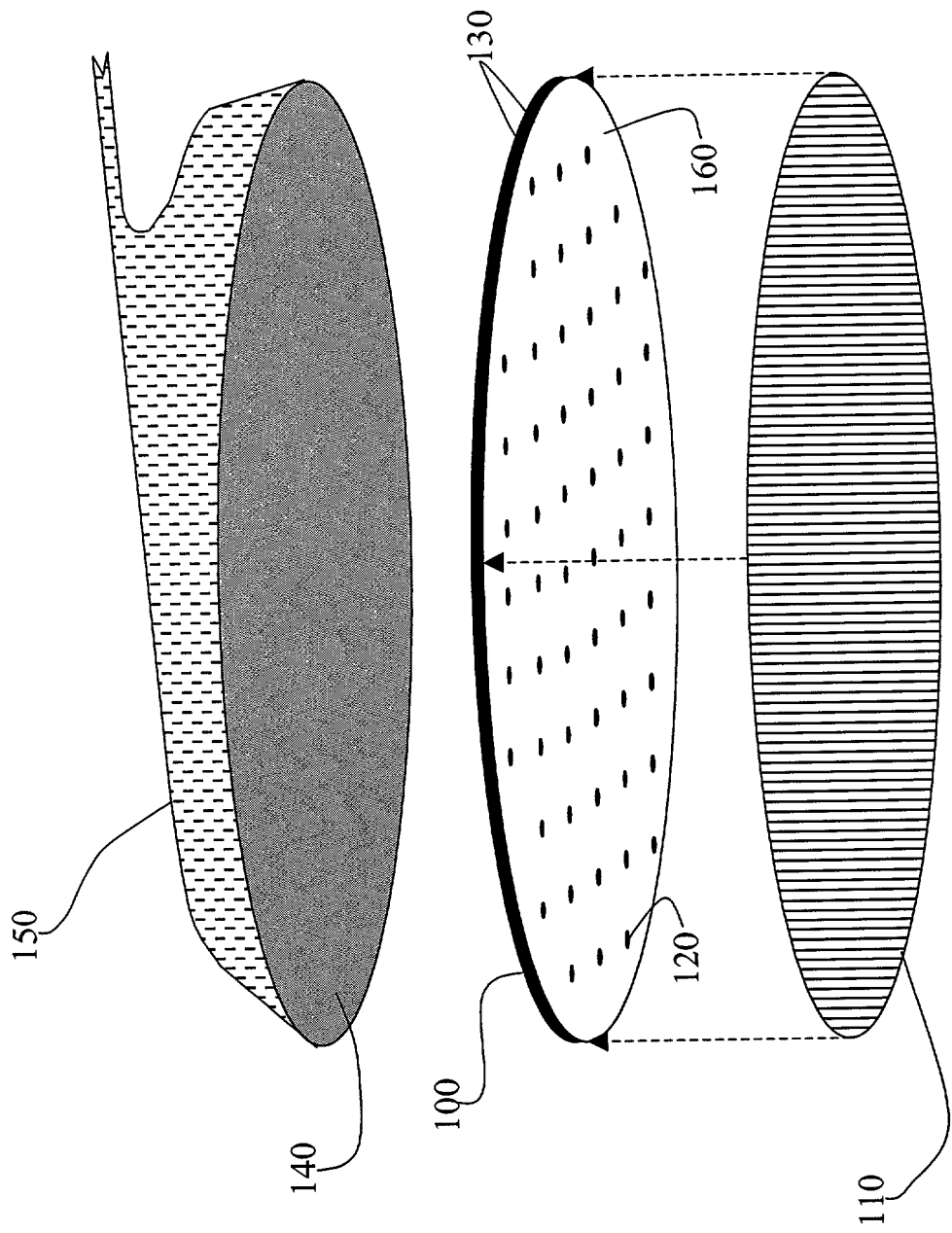


FIGURE 1A

150

140

FIGURE 1B

Vacuum source

Vacuum attachment

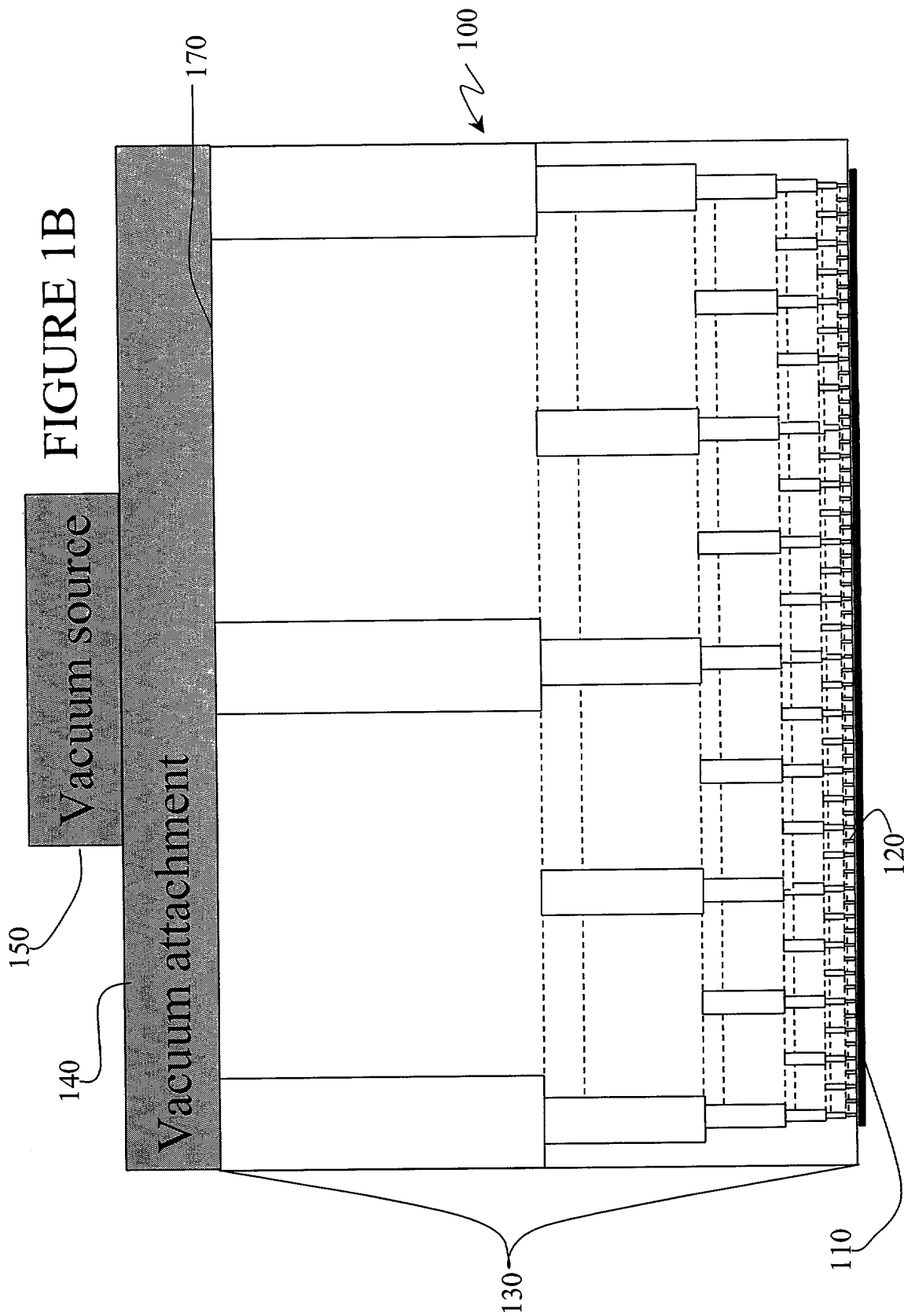
170

100

130

110

120



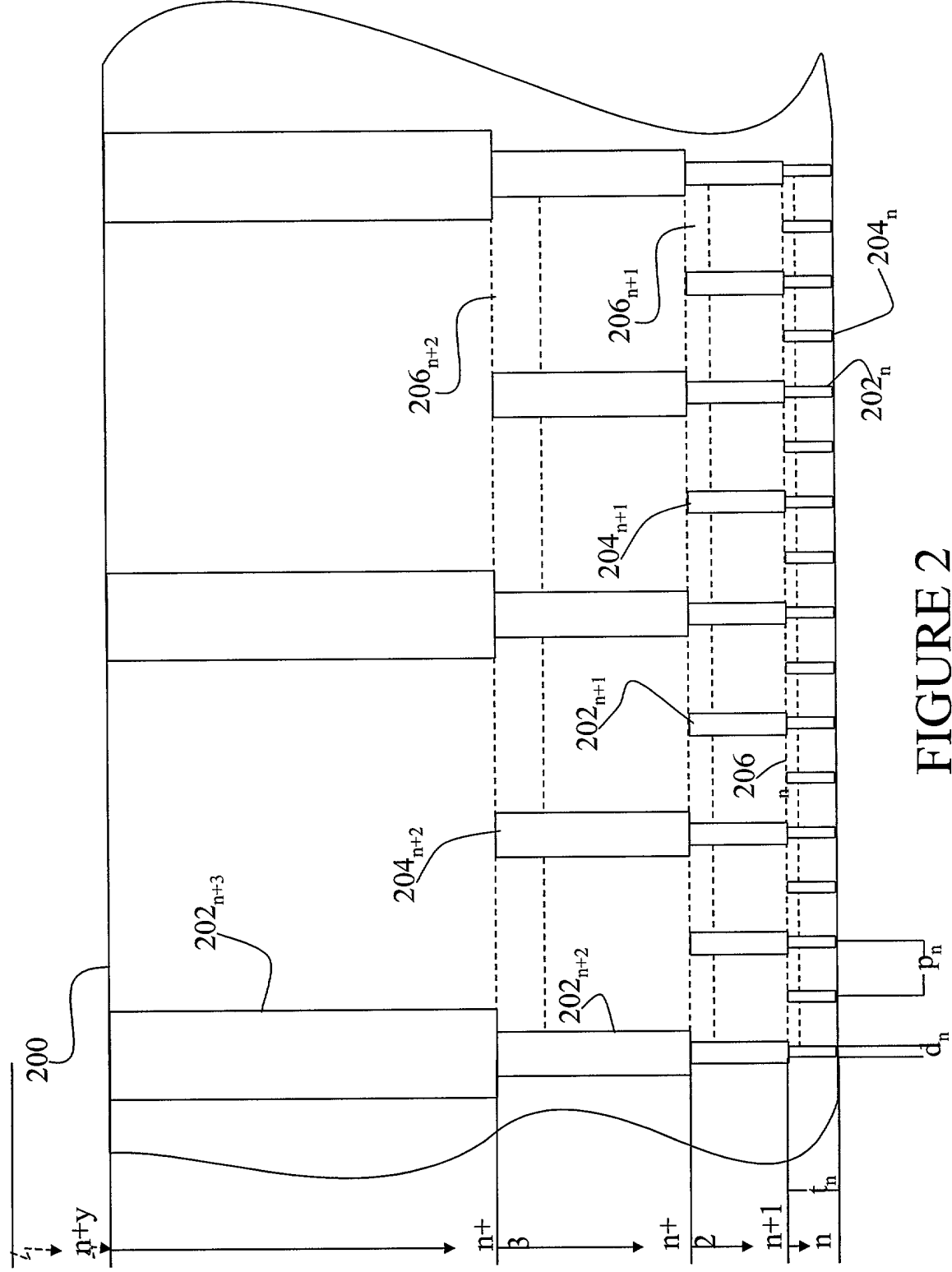


FIGURE 2

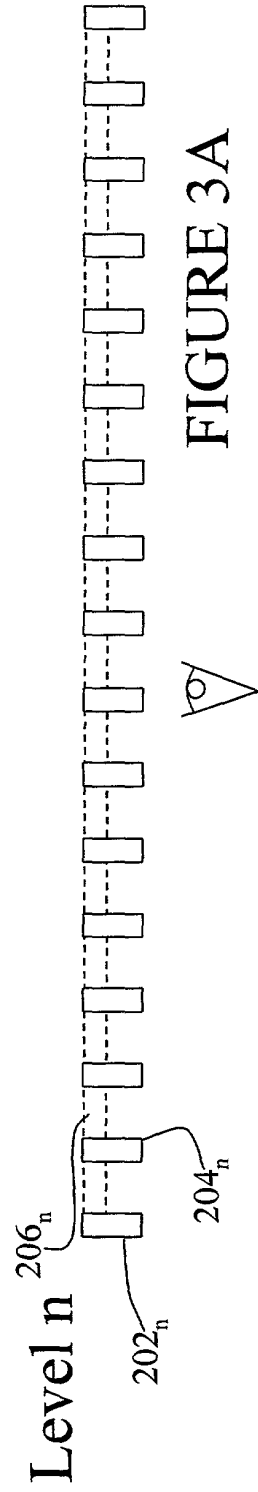
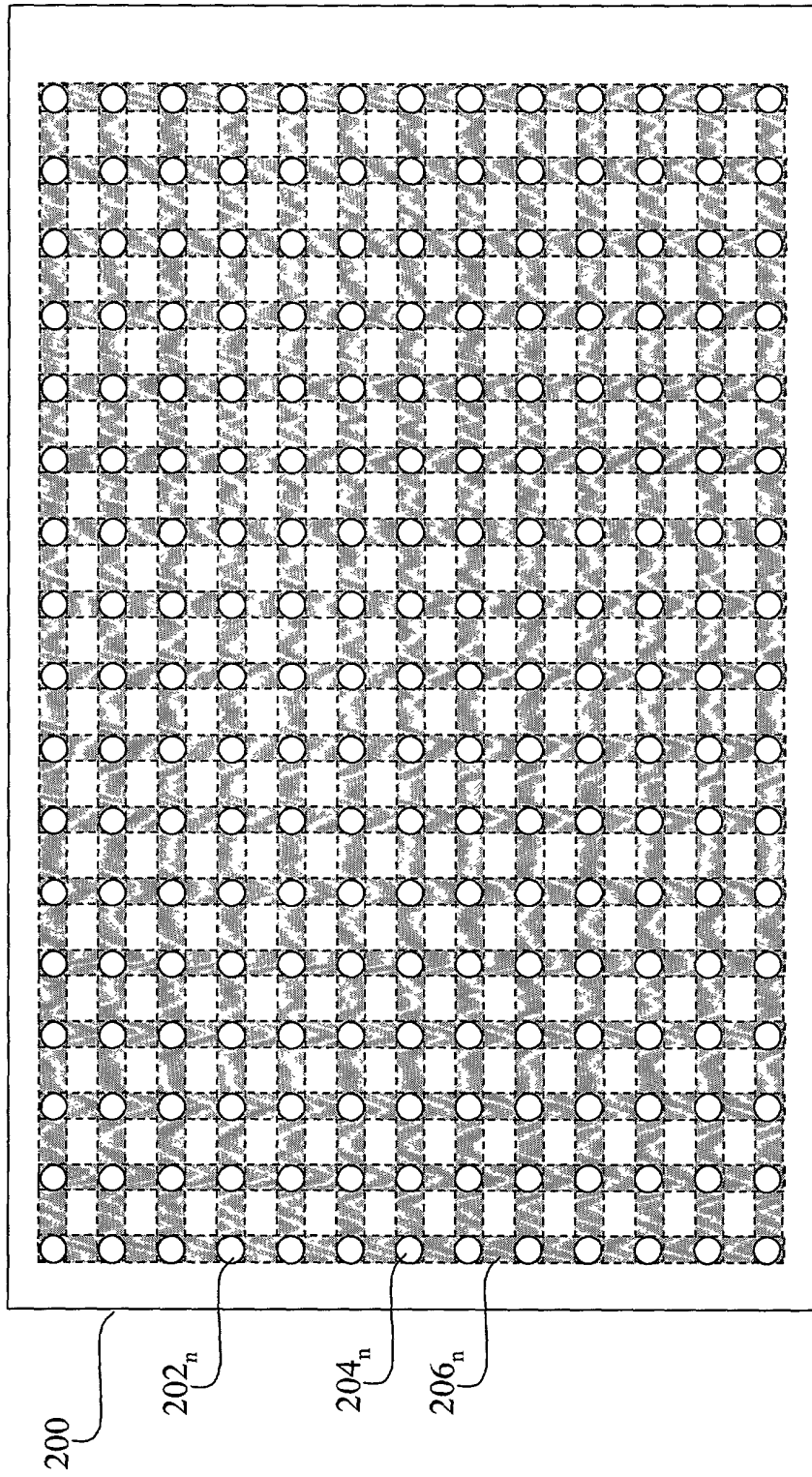
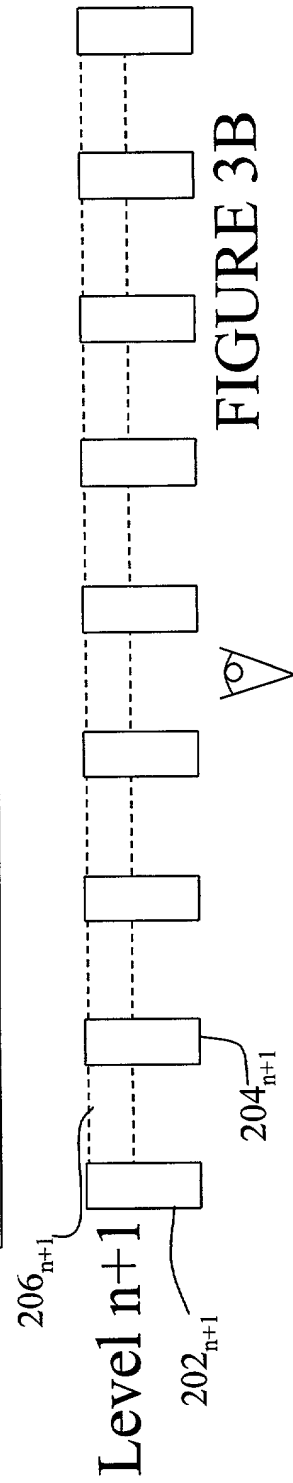
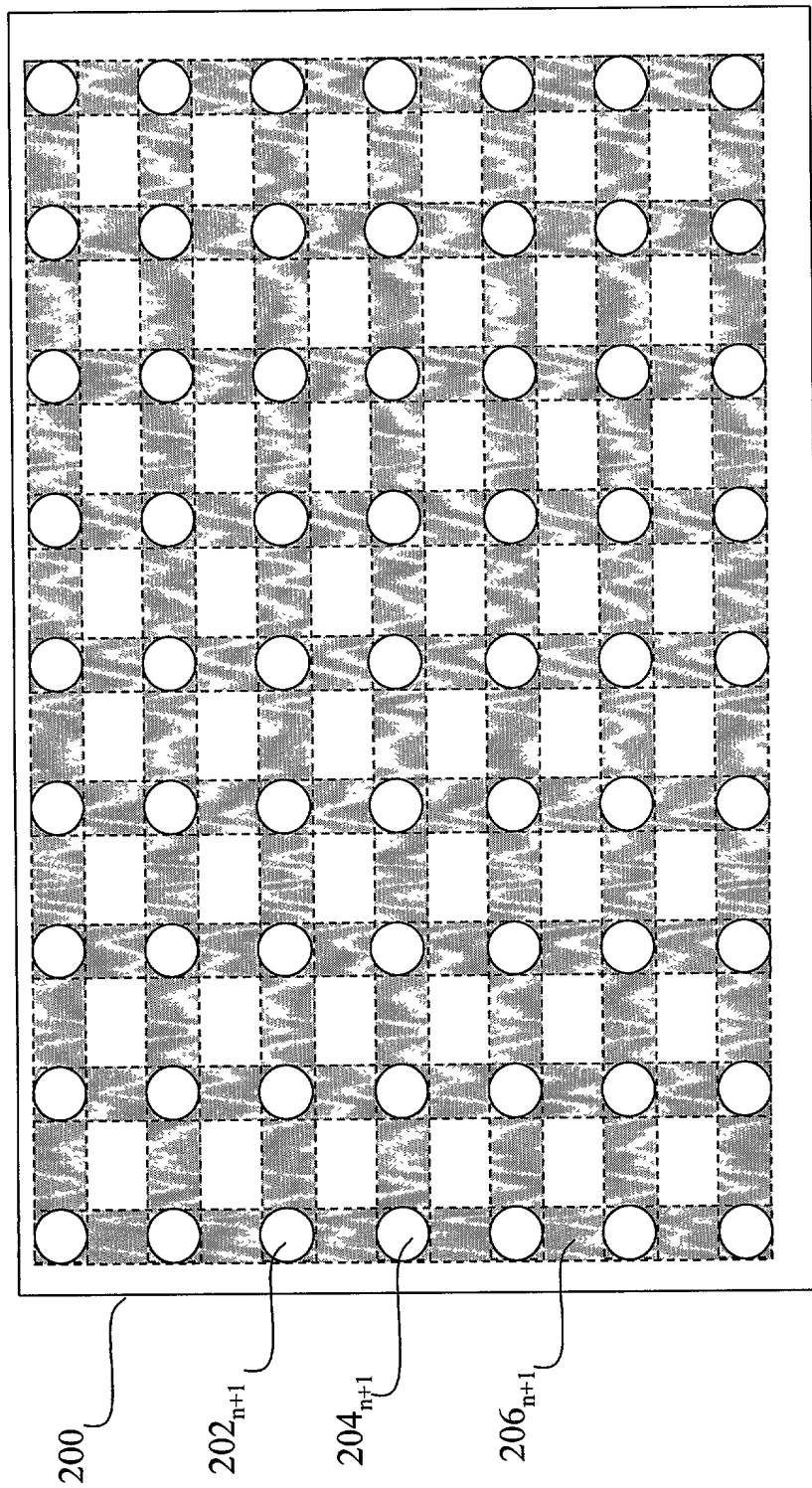
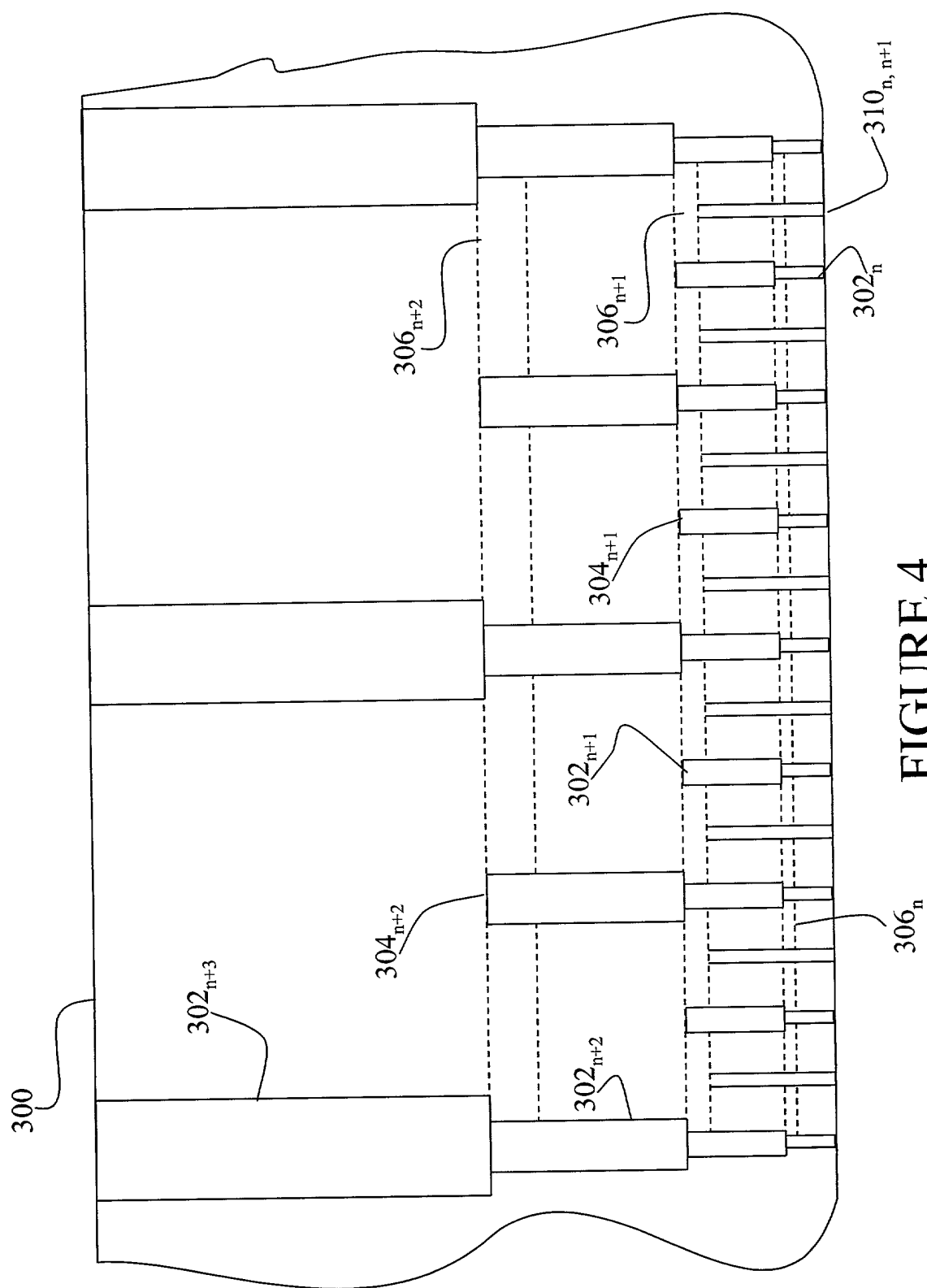


FIGURE 3A





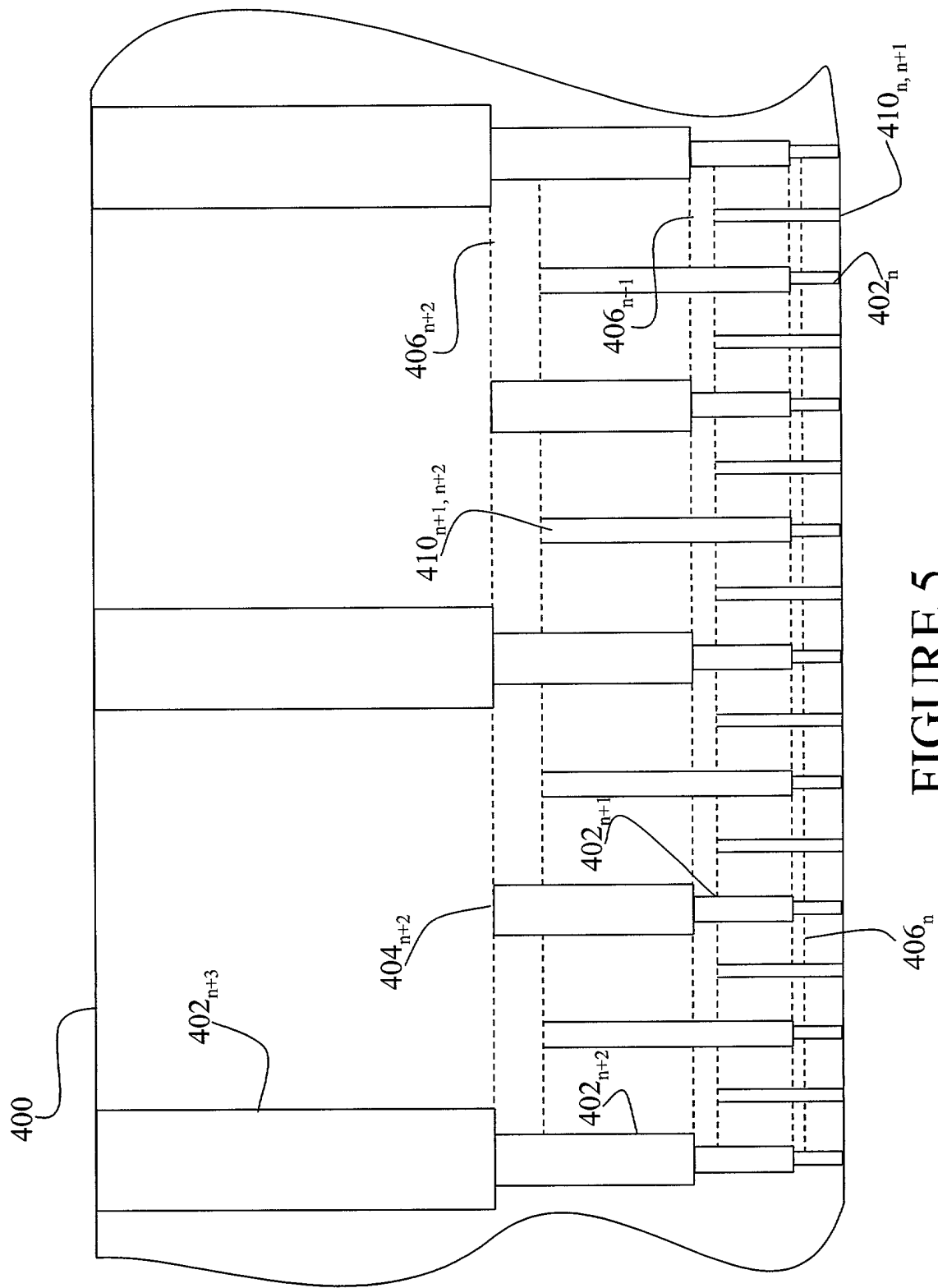


FIGURE 5

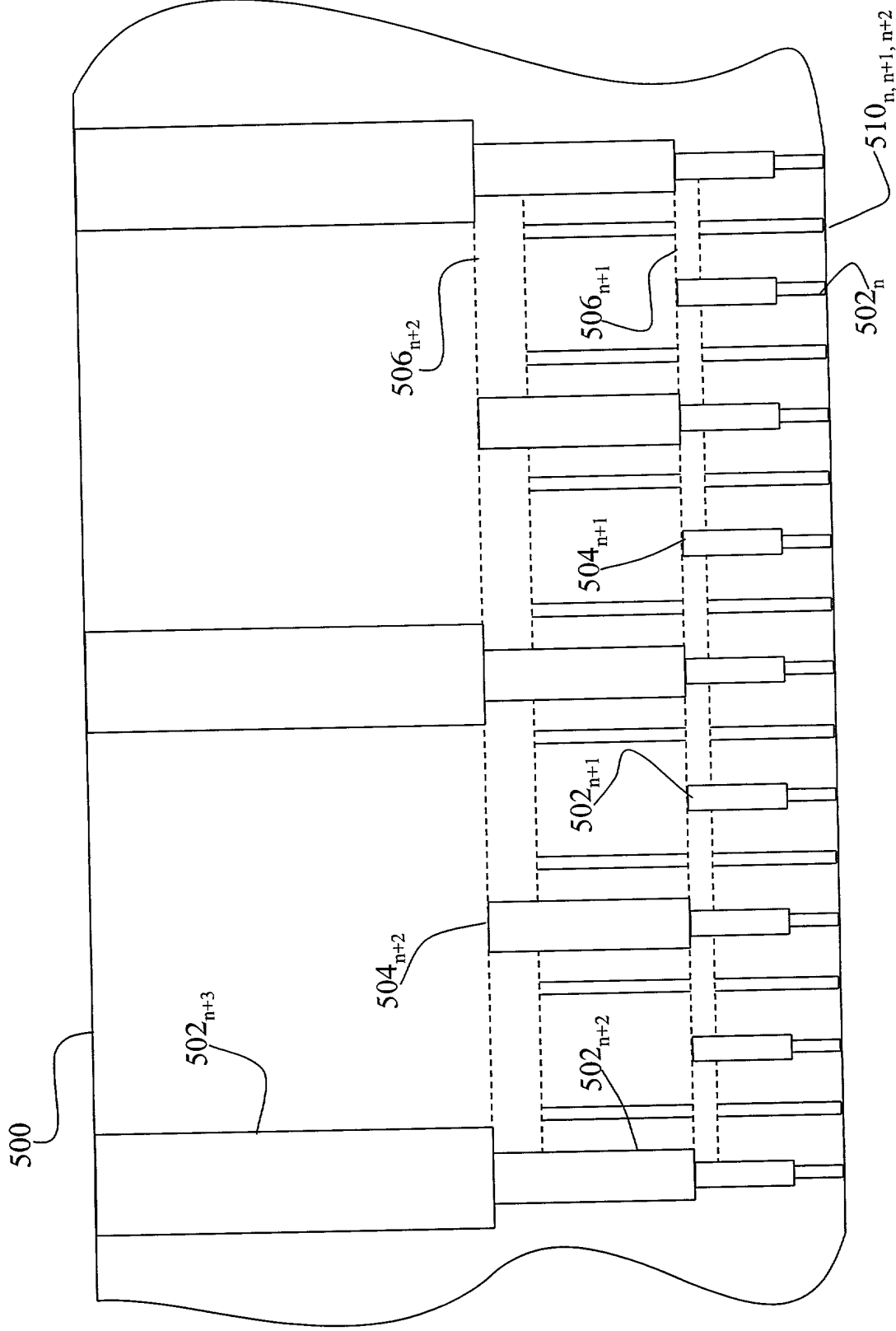


FIGURE 6

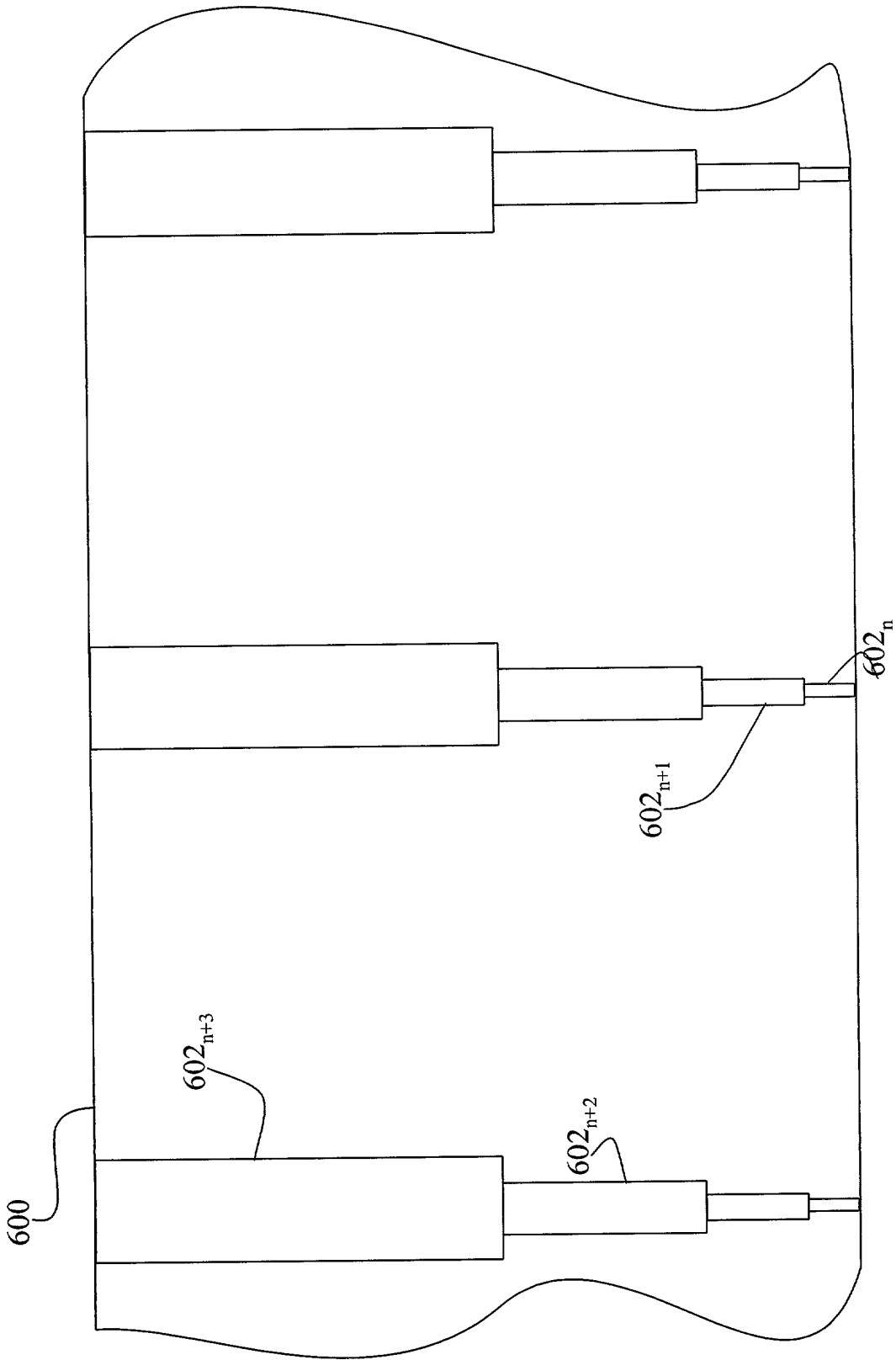


FIGURE 7

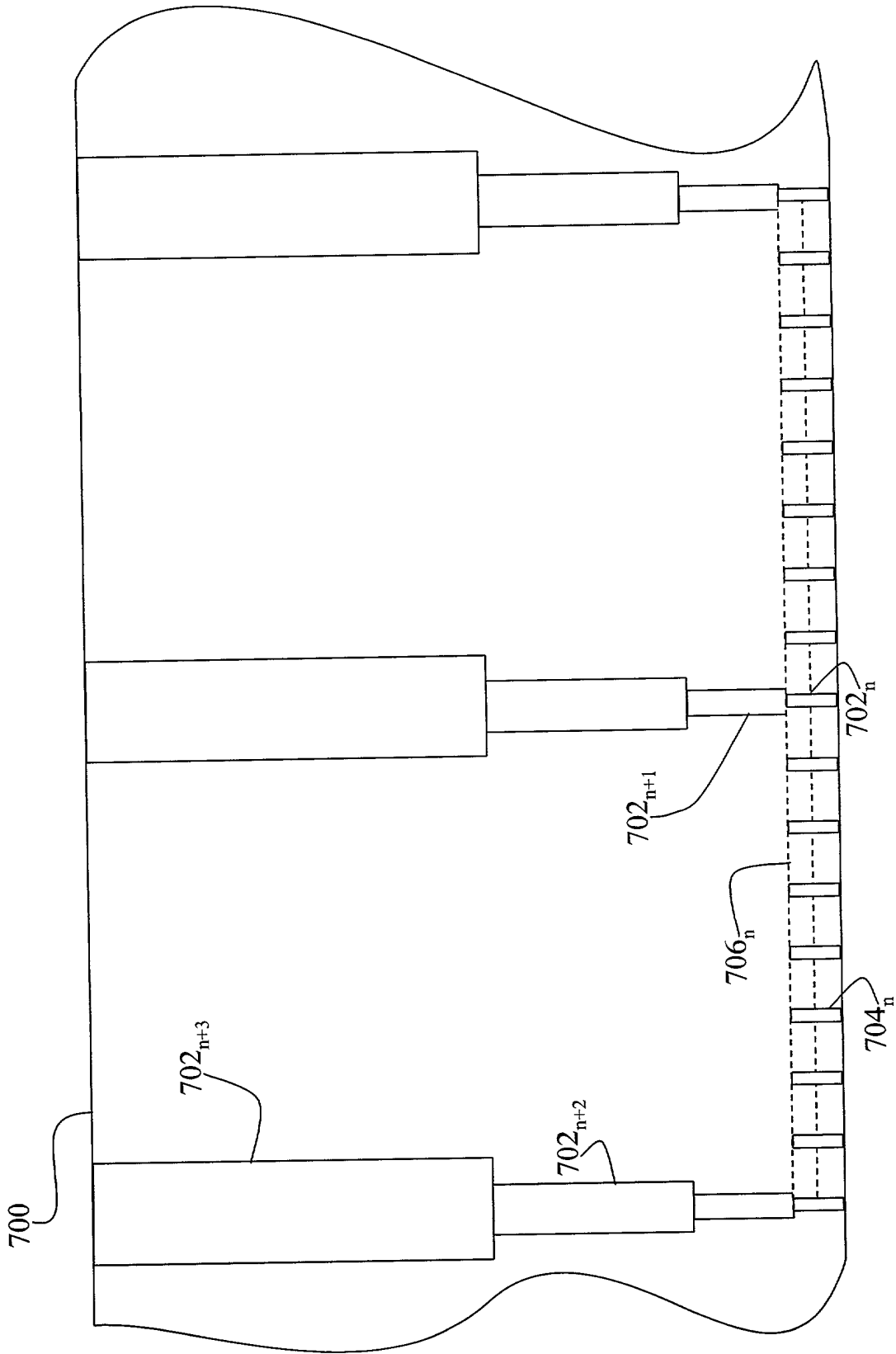


FIGURE 8

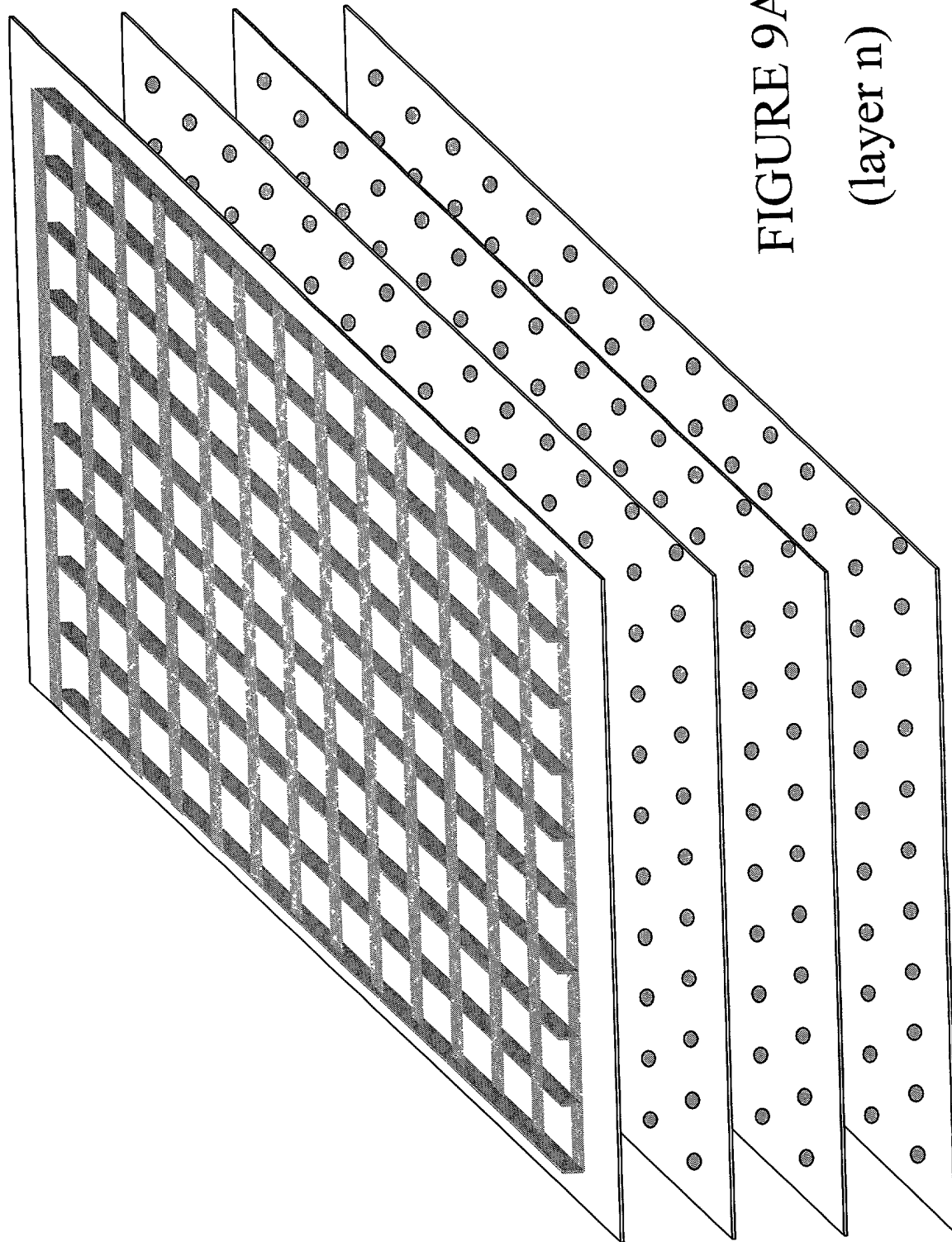


FIGURE 9A
(layer n)

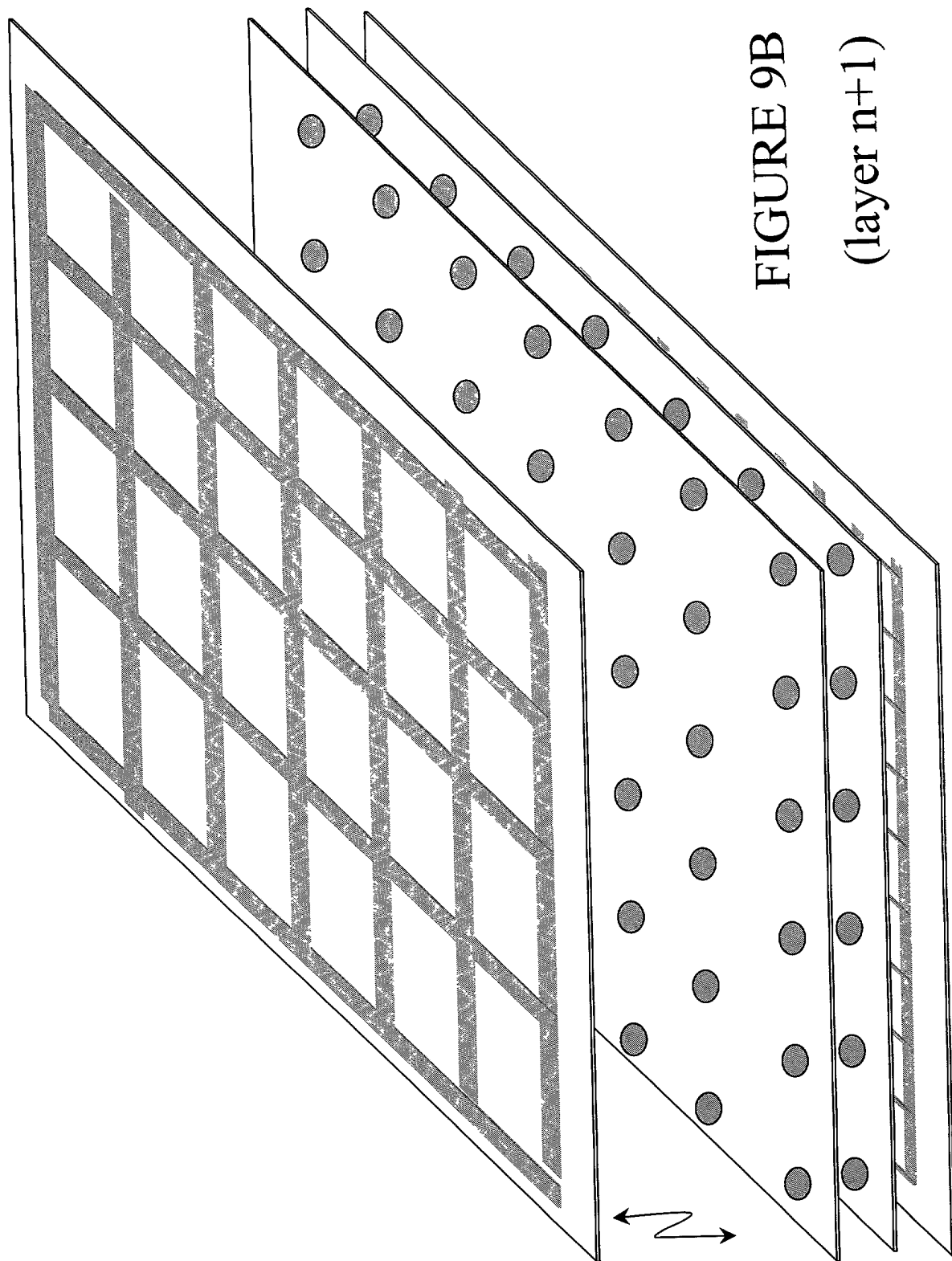


FIGURE 9B
(layer n+1)

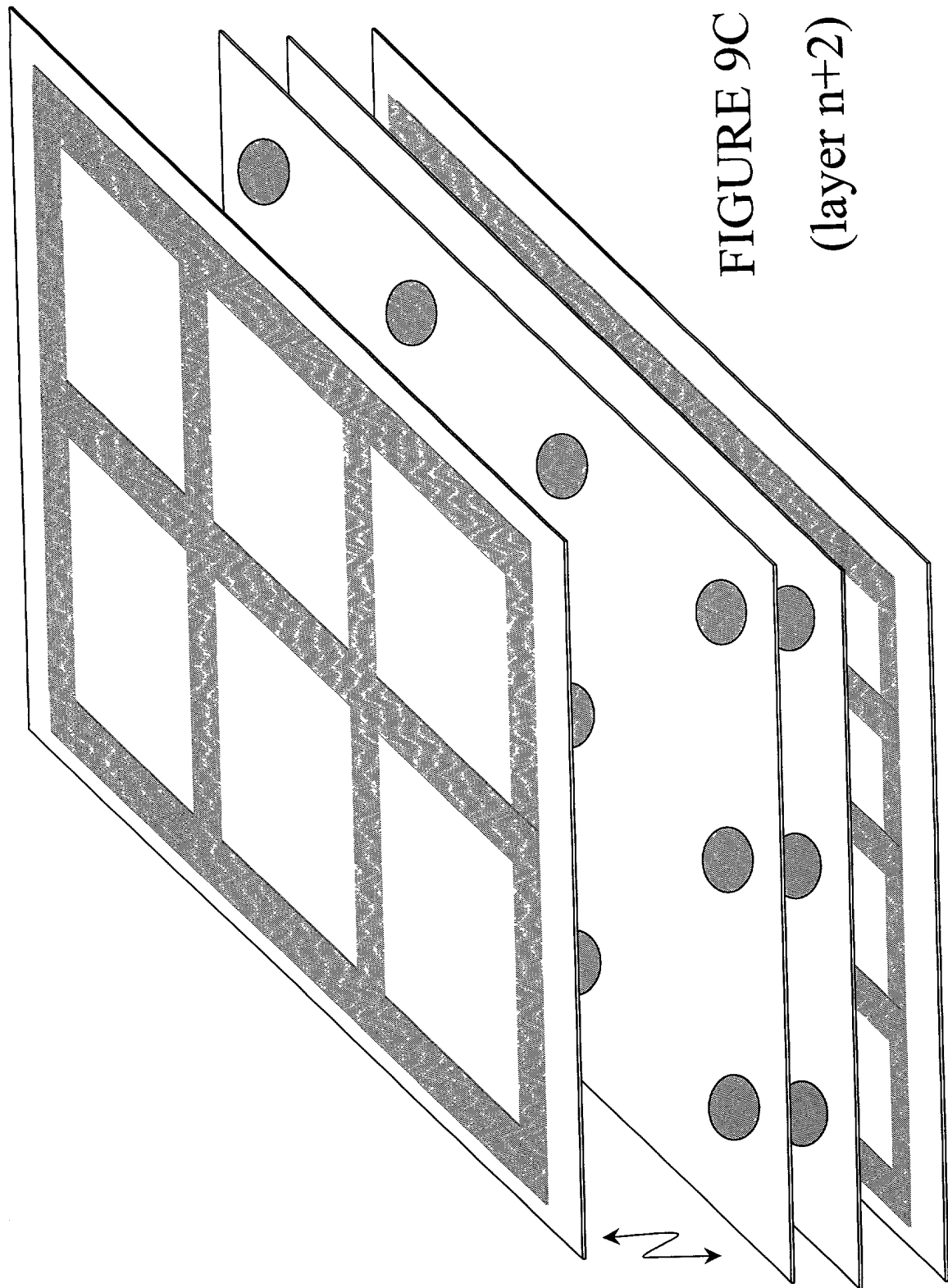


FIGURE 9C
(layer n+2)

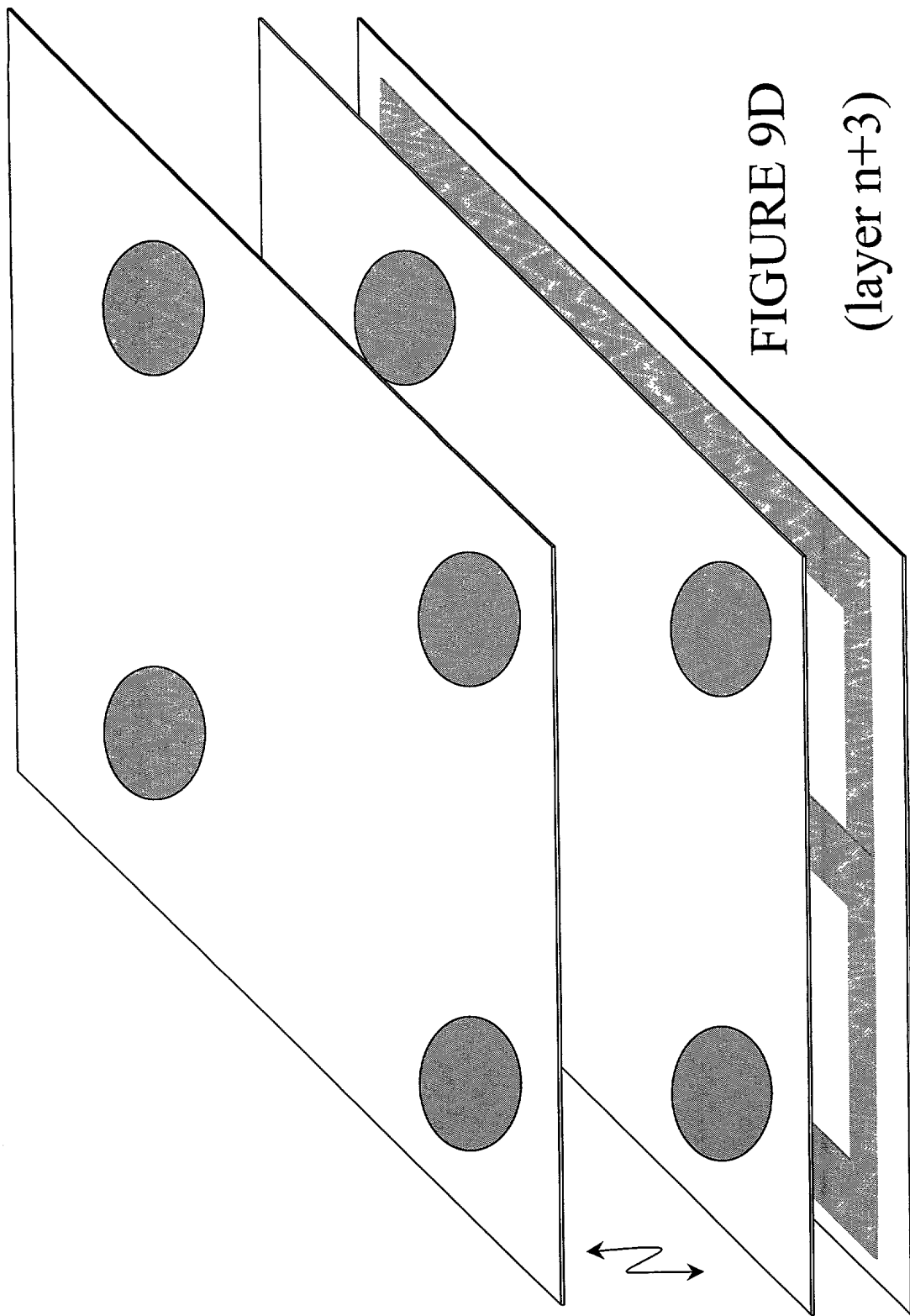


FIGURE 9D
(layer $n+3$)

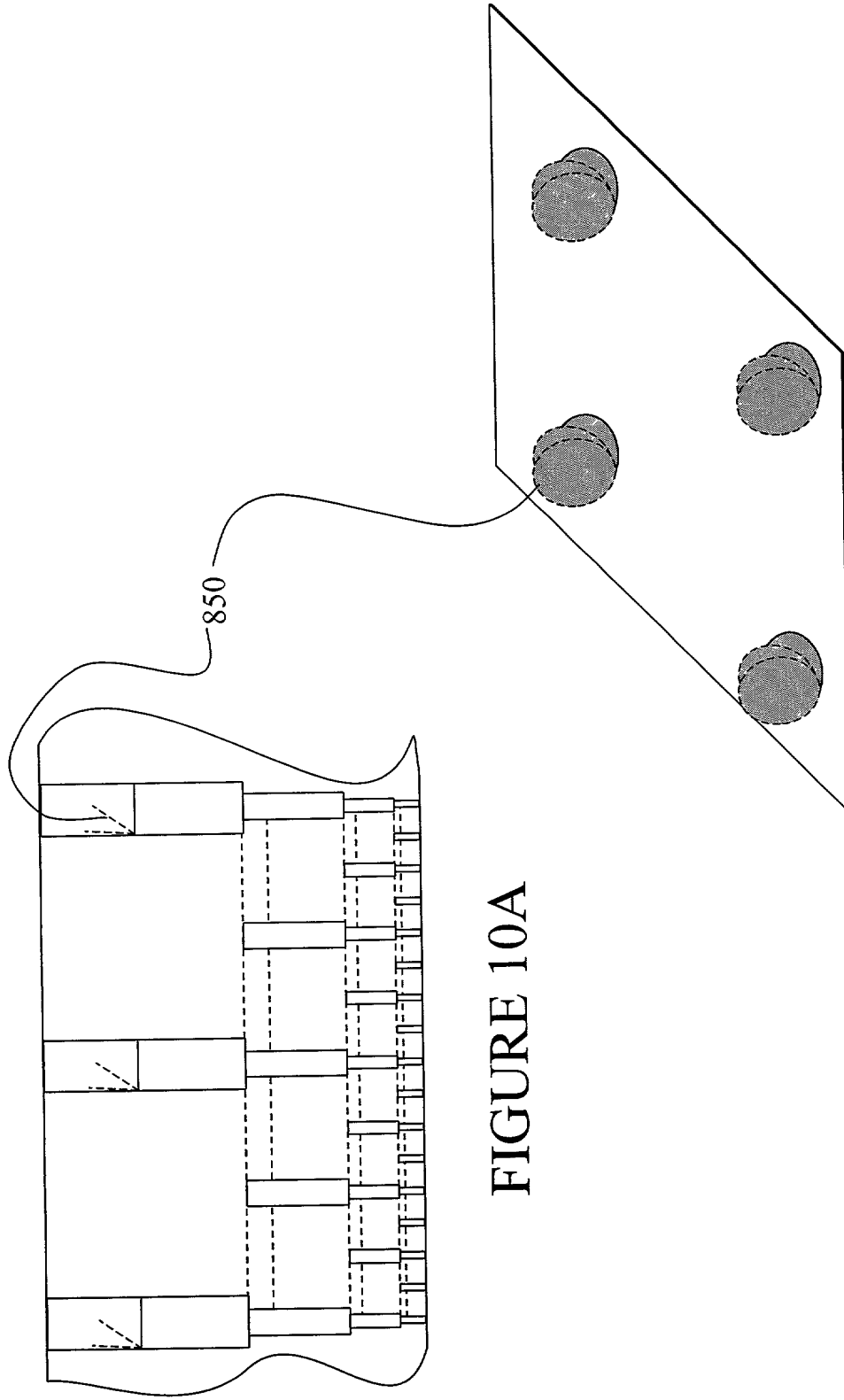


FIGURE 10A

FIGURE 10B

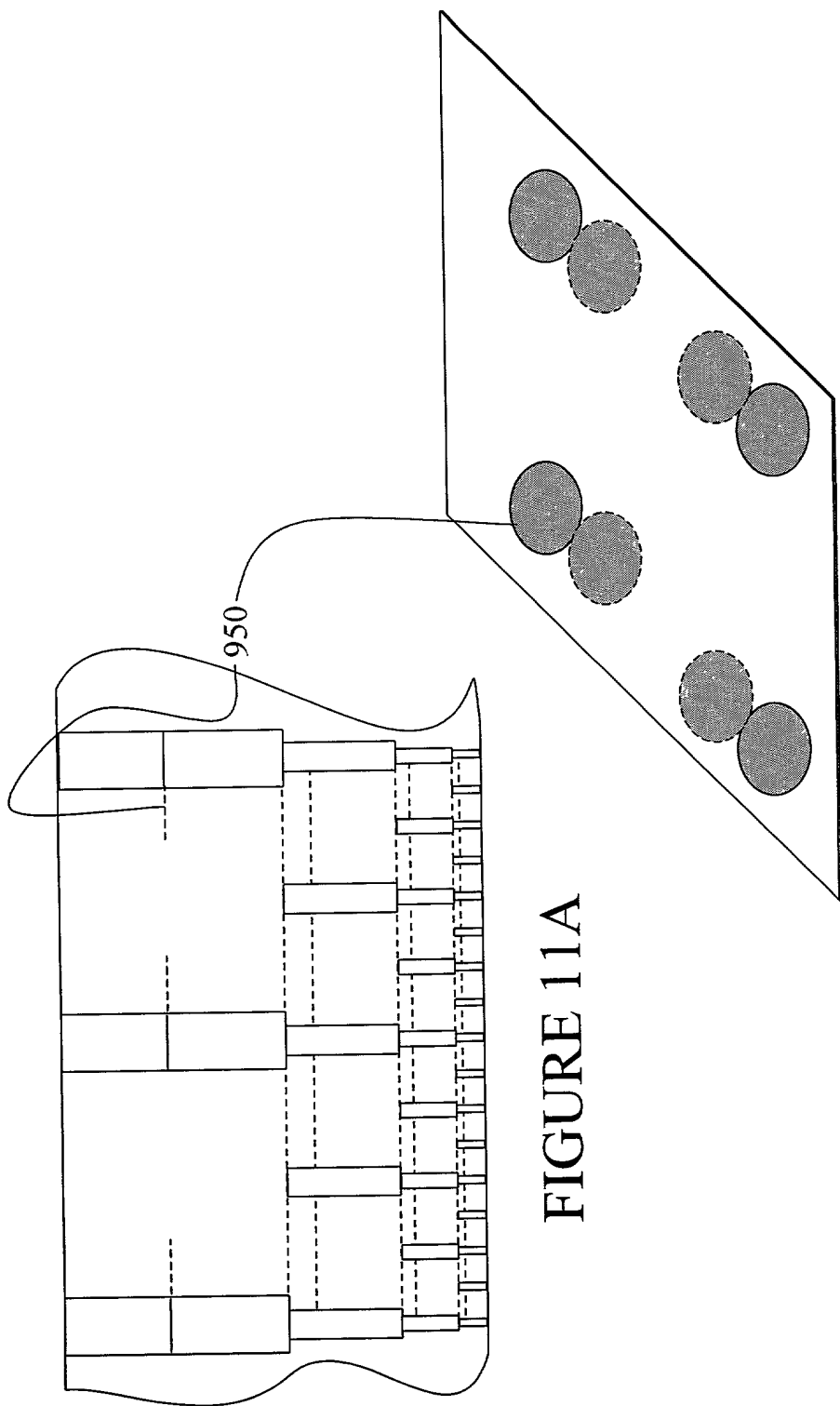


FIGURE 11B

FIGURE 11A